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Residence Information (Select One)  US Residency  Non US Residency  Active US Military Service  City Isehara, Kanagawa  Country Of Residence  JP  Citizenship under 37 CFR 1.41(b) i JP  Mailing Address of Applicant:  Address 1					Middle Na	me		Family	Name			Suffix
City Isehara, Kanagawa Country Of Residencei JP  Citizenship under 37 CFR 1.41(b) i JP  Mailing Address of Applicant:  Address 1		Kiyoshi						KATO				
Citizenship under 37 CFR 1.41(b) i JP  Mailing Address of Applicant:  Address 1 c/o Semiconductor Energy Laboratory Co., Ltd.  Address 2 398, Hase  City Atsugi-shi, Kanagawa-ken State/Province  Postal Code 243-0036 Countryi JP  All Inventors Must Be Listed - Additional Inventor Information blocks may be generated within this form by selecting the Add button.  Correspondence Information:  Enter either Customer Number or complete the Correspondence Information section below. For further information see 37 CFR 1.33(a).  An Address is being provided for the correspondence Information of this application.  Customer Number 26171  Email Address hayden@fr.com Add Email Remove Email  Application Information:  Title of the Invention SEMICONDUCTOR INTEGRATED CIRCUIT AND DESIGN METHOD THEREOF  Attorney Docket Number 12732-335US1 Small Entity Status Claimed  Application Type Nonprovisional  Subject Matter Utility  Suggested Class (if any) Sub Class (if any)  Suggested Technology Center (if any)	Resid	ence Informa	tion (Selec	t One) 🔘 l	JS Residend	cy   No	on US Res	sidency	O Active US	Militar	y Service	<del></del>
Mailing Address of Applicant:  Address 1	City	Isehara, Kana	gawa	Cou	intry Of Re	esidencei	JP					
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Address 2 398, Hase  City Atsugi-shi, Kanagawa-ken State/Province  Postal Code 243-0036 Countryi JP  All Inventors Must Be Listed - Additional Inventor Information blocks may be generated within this form by selecting the Add button.  Correspondence Information:  Enter either Customer Number or complete the Correspondence Information section below. For further information see 37 CFR 1.33(a).  An Address is being provided for the correspondence Information of this application.  Customer Number 26171  Email Address hayden@fr.com Add Email Remove Email  Application Information:  Title of the Invention SEMICONDUCTOR INTEGRATED CIRCUIT AND DESIGN METHOD THEREOF  Attorney Docket Number 12732-335US1 Small Entity Status Claimed Application Type Nonprovisional  Subject Matter Utility  Suggested Class (if any) Sub Class (if any)  Suggested Technology Center (if any)	Mailing	g Address of	Applicant:	<b>'</b>								
City Atsugi-shi, Kanagawa-ken State/Province  Postal Code 243-0036 Countryi JP  All Inventors Must Be Listed - Additional Inventor Information blocks may be generated within this form by selecting the Add button.  Correspondence Information:  Enter either Customer Number or complete the Correspondence Information see 37 CFR 1.33(a).  An Address is being provided for the correspondence Information of this application.  Customer Number 26171  Email Address hayden@fr.com Add Email Remove Email  Application Information:  Title of the Invention SEMICONDUCTOR INTEGRATED CIRCUIT AND DESIGN METHOD THEREOF Attorney Docket Number 12732-335US1 Small Entity Status Claimed Application Type Nonprovisional  Subject Matter Utility  Suggested Class (if any) Sub Class (if any)  Suggested Technology Center (if any)	Addres	ss 1	c/o Ser	miconductor E	nergy Labo	ratory Co., Ltd	d.					
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Application Data	Silect St Cl K 1.70	Application Number					
Title of Invention	SEMICONDUCTOR INTEGR	ATED CIRCUIT AND DESIGN	I METHOD THEREOF				
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Request Early P	ublication (Fee required a	t time of Request 37 CFR 1	.219)				
and certify that t	the invention disclosed in	that the attached application the attached application has er a multilateral agreement	not been and will not	be the subject of an			
Representative	Information:						
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Please Select One:	Customer Number	US Patent Practition	ner US Represe	ntative (37 CFR 11.9)			
Customer Number	26171						
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Application Da	ta Sheet 37 CFR 1.76	Attorney Docket Number	12732-335US1
Application Data offeet 37 Cr K 1.70		Application Number	
Title of Invention	SEMICONDUCTOR INTEGRATED CIRCUIT AND DESIGN METHOD THEREOF		

## **Assignee Information:**

Providing this information in the application data sheet does not substitute for compliance with any requirement of part 3 of Title 37 of the CFR to have an assignment recorded in the Office.						
Assignee 1		Remove				
If the Assignee is an Organization	ganization check here.					
Organization Name	Semiconductor Energy Laboratory Co	emiconductor Energy Laboratory Co., Ltd.				
Mailing Address Inform	mation:					
Address 1	398, Hase	398, Hase				
Address 2						
City	Atsugi-shi, Kanagawa-ken	State/Province				
Country   JP		Postal Code	243-0036			
Phone Number	011-81-46-248-1131	Fax Number	011-81-46-270-2081			
Email Address						
Additional Assignee Data may be generated within this form by selecting the Add button.						

## Signature:

A signature of the applicant or representative is required in accordance with 37 CFR 1.33 and 10.18. Please see 37 CFR 1.4(d) for the form of the signature.								
Signature	Signature /John F. Hayden/			Date (YYYY-MM-DD)	2006-04-27			
First Name	John	Last Name	Hayden	Registration Number	37,640			

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